

SNOS100B - AUGUST 1998-REVISED APRIL 2013

54AC251 • 54ACT251 8-Input Multiplexer with TRI-STATE Output

Check for Samples: 54AC251, 54ACT251

FEATURES

- I_{CC} Reduced by 50%
- Multifunctional Capability
- On-Chip Select Logic Decoding
- Inverting and Noninverting TRI-STATE Outputs
- Outputs Source/Sink 24 mA
- 'ACT251 has TTL-Compatible Inputs
- Standard Military Drawing (SMD)

'AC251: 5962-87692'ACT251: 5962-89599

Logic Symbols

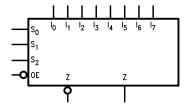


Figure 1.

DESCRIPTION

The 'AC/'ACT251 is a high-speed 8-input digital multiplexer. It provides, in one package, the ability to select one bit of data from up to eight sources. It can be used as universal function generator to generate any logic function of four variables. Both true and complementary outputs are provided.

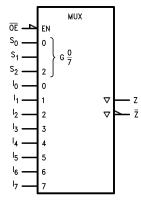


Figure 2. IEEE/IEC

PIN DESCRIPTION

Pin Names	Description
S ₀ -S ₂	Select Inputs
ŌĒ	TRI-STATE Output Enable Input
I ₀ -I ₇	Multiplexer Inputs
Z	TRI-STATE Multiplexer Output
Z	Complementary TRI-STATE Multiplexer
	Output

M

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Connection Diagram

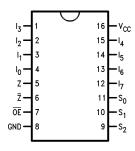


Figure 3. 16-Pin CERDIP or CLGA See NAD0016A Package

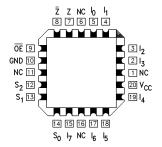


Figure 4. 20-Pin LCCC See NAJ0020A Package

FUNCTIONAL DESCRIPTION

This device is a logical implementation of a single-pole, 8-position switch with the switch position controlled by the state of three Select inputs, S_0 , S_1 , S_2 . Both true and complementary outputs are provided. The Output Enable input (\overline{OE}) is active LOW. When it is activated, the logic function provided at the output is:

$$\mathbf{Z} = \overline{\mathbf{OE}} \bullet (I_0 \bullet \overline{S}_0 \bullet \overline{S}_1 \bullet \overline{S}_2 + I_1 \bullet S_0 \bullet \overline{S}_1 \bullet \overline{S}_2 + I_2 \bullet \overline{S}_0 \bullet S_1 \bullet \overline{S}_2 + I_3 \bullet S_0 \bullet S_1 \bullet \overline{S}_2 + I_4 \bullet \overline{S}_0 \bullet \overline{S}_1 \bullet S_2 + I_5 \bullet S_0 \bullet \overline{S}_1 \bullet S_2 + I_6 \bullet \overline{S}_0 \bullet S_1 \bullet S_2 + I_7 \bullet S_0 \bullet S_1 \bullet S_2)$$

When the Output Enable is HIGH, both outputs are in the high impedance (High Z) state. This feature allows multiplexer expansion by tying the outputs of up to 128 devices together. When the outputs of the TRI-STATE devices are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. The Output Enable signals should be designed to ensure there is no overlap in the active-LOW portion of the enable voltages.

TRUTH TABLE (1)

	Inputs				puts
ŌĒ	S ₂	S ₁	S ₀	Z	Z
Н	X	X	X	Z	Z
L	L	L	L	Ī ₀	I ₀
L	L	L	Н	Ī ₁	I ₁
L	L	Н	L	Ī ₂	l ₂
L	L	Н	Н	Ī ₃	l ₃
L	Н	L	L	\bar{I}_4	I ₄
L	Н	L	Н	Ī ₅	l ₅
L	Н	Н	L	Ī ₆	I ₆
L	Н	Н	Н	Ī ₇	I ₇

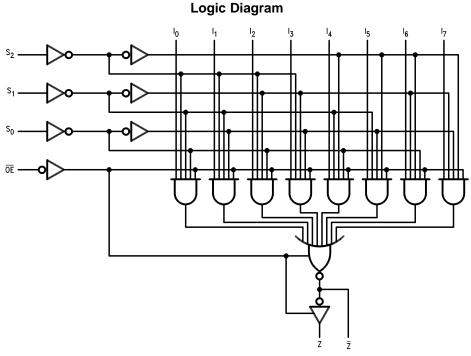
(1) H = HIGH Voltage Level

L = LOW Voltage Level

X = Immaterial

Z = High Impedance

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Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ABSOLUTE MAXIMUM RATINGS (1)(2)

Supply Voltage (V _{CC})		-0.5V to +7.0V
DC Input Diode Current (I _{IK})	V _I = −0.5V	−20 mA
	$V_I = V_{CC} + 0.5V$	+20 mA
DC Input Voltage (V _I)		-0.5V to V _{CC} + 0.5V
DC Output Diode Current (I _{OK})	V _O = −0.5V	−20 mA
	$V_{O} = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V _O)		-0.5V to V _{CC} + 0.5V
DC Output Source or Sink Current (I _O)		±50 mA
DC V _{CC} or Ground Current per Output Pin (I _{CC} or I _{GND})		±50 mA
Storage Temperature (T _{STG})		−65°C to +150°C
Junction Temperature (T _J)	CDIP	175°C

⁽¹⁾ Absolute Maximum Ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Texas Instruments does not recommend operation of FACT[®] circuits outside databook specifications.

RECOMMENDED OPERATING CONDITIONS

Supply Voltage (V _{CC})	'AC	2.0V to 6.0V
	'ACT	4.5V to 5.5V
Input Voltage (V _I)		0V to V _{CC}
Output Voltage (V _O)		0V to V _{CC}
Operating Temperature (T _A)	54AC/ACT	−55°C to +125°C
Minimum Input Edge Rate (ΔV/Δt)	V_{IN} from 30% to 70% of V_{CC}	
'AC Devices	V _{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate (ΔV/Δt)	V _{IN} from 0.8V to 2.0V	
'ACT Devices	V _{CC} @ 4.5V, 5.5V	125 mV/ns

DC CHARACTERISTICS FOR 'AC FAMILY DEVICES

		V _{CC} (V)	54AC		
Symbol	Parameter	(V)	T _A = −55°C to +125°C	Units	Conditions
			Ensured Limits		
V _{IH}	Minimum High Level Input	3.0	2.1		V _{OUT} = 0.1V
	Voltage	4.5	3.15	V	$V_{OUT} = 0.1V$ or $V_{CC} = 0.1V$
		5.5	3.85		
V _{IL}	Maximum Low Level Input	3.0	0.9		V _{OUT} = 0.1V
Voltage	Voltage	4.5	1.35	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		5.5	1.65		

⁽²⁾ If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.

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DC CHARACTERISTICS FOR 'AC FAMILY DEVICES (continued)

		V _{CC}	54AC		
Symbol	Parameter	(V)	T _A = −55°C to +125°C	Units	Conditions
			Ensured Limits		
V _{OH}	Minimum High Level Output	3.0	2.9		I _{OUT} = -50 μA
	Voltage	4.5	4.4	V	
		5.5	5.4		
					$V_{IN} = V_{IL} \text{ or } V_{IH}^{(1)}$
		3.0	2.4	V	I _{OH} = −12 mA
		4.5	3.7		$I_{OH} = -24 \text{ mA}$
		5.5	4.7		I _{OH} = −24 mA
V_{OL}	Maximum Low Level Output	3.0	0.1		$I_{OUT} = 50 \mu A$
	Voltage	4.5	0.1	V	
		5.5	0.1		
					$V_{IN} = V_{IL} \text{ or } V_{IH}^{(1)}$
		3.0	0.50	V	$I_{OL} = 12 \text{ mA}$
		4.5	0.50		$I_{OL} = 24 \text{ mA}$
		5.5	0.50		$I_{OL} = 24 \text{ mA}$
I _{IN}	Maximum Input Leakage Current	5.5	±1.0	μΑ	$V_I = V_{CC}$, GND
I _{OZ}	Maximum TRI-STATE Current				V_{I} (OE) = V_{IL} , V_{IH}
		5.5	±5.0	μΑ	$V_{I} = V_{CC}, V_{GND}$
					$V_O = V_{CC}$, GND
I _{OLD}	Minimum Dynamic Output	5.5	50	mA	V _{OLD} = 1.65V Max
I _{OHD}	Current (2)	5.5	-50	mA	V _{OHD} = 3.85V Min
I _{CC}	Maximum Quiescent Supply Current	5.5	80.0	μA	$V_{IN} = V_{CC}$ or GND

⁽¹⁾ All outputs loaded; thresholds on input associated with output under test.

DC CHARACTERISTICS FOR 'ACT FAMILY DEVICES

		V _{CC} 54ACT			
Symbol	Parameter	(V)	T _A = -55°C to +125°C	Units	Conditions
			Ensured Limits		
V _{IH}	Minimum High Level Input	4.5	2.0	V	V _{OUT} = 0.1V
	Voltage	5.5	2.0	V	or V _{CC} - 0.1V
V_{IL}	Maximum Low Level Input	4.5	0.8	V	V _{OUT} = 0.1V
	Voltage	5.5	0.8	V	or V _{CC} - 0.1V
V _{OH}	Minimum High Level Output	4.5	4.4	V	I _{OUT} = -50 μA
	Voltage	5.5	5.4	V	
					$V_{IN} = V_{IL} \text{ or } V_{IH}^{(1)}$
		4.5	3.70	V	$I_{OH} = -24 \text{ mA}$
		5.5	4.70		$I_{OH} = -24 \text{ mA}$
V _{OL}	Maximum Low Level Output	4.5	0.1	V	I _{OUT} = 50 μA
	Voltage	5.5	0.1	V	
					$V_{IN} = V_{IL} \text{ or } V_{IH}^{(1)}$
		4.5	0.50	V	$I_{OL} = 24 \text{ mA}$
		5.5	0.50		$I_{OL} = 24 \text{ mA}$

⁽²⁾ Maximum test duration 2.0 ms, one output loaded at a time.

⁽¹⁾ All outputs loaded; thresholds on input associated with output under test.



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DC CHARACTERISTICS FOR 'ACT FAMILY DEVICES (continued)

		V _{CC} (V)	54ACT		
Symbol	Parameter	(V)	T _A = −55°C to +125°C	Units	Conditions
			Ensured Limits		
I _{IN}	Maximum Input Leakage Current	5.5	±1.0	μΑ	$V_I = V_{CC}$, GND
l _{OZ}	Maximum TRI-STATE Current	5.5	±5.0	μΑ	$V_I = V_{IL}, V_{IH}$ $V_O = V_{CC}, GND$
I _{CCT}	Maximum I _{CC} /Input	5.5	1.6	mA	$V_I = V_{CC} - 2.1V$
I _{OLD}	Minimum Dynamic Output	5.5	50	mA	V _{OLD} = 1.65V Max
I _{OHD}	Current (2)	5.5	-50	mA	V _{OHD} = 3.85V Min
Icc	Maximum Quiescent Supply Current	5.5	80.0	μΑ	V _{IN} = V _{CC} or GND

⁽²⁾ Maximum test duration 2.0 ms, one output loaded at a time.

AC ELECTRICAL CHARACTERISTICS

Symbol	Parameter		54	4AC	
		V _{CC} (V) (1)	to +	T _A = -55°C to +125°C C _L = 50 pF	
			Min	Max	
t _{PLH}	Propagation Delay S_n to Z or \overline{Z}	3.3	1.0	21.0	
		5.0	1.0	15.5	ns
t _{PHL}	Propagation Delay S_n to Z or \overline{Z}	3.3	1.0	21.0	
		5.0	1.0	15.5	ns
t _{PLH}	Propagation Delay I _n to Z or Z	3.3	1.0	17.0	
		5.0	1.0	12.0	ns
t _{PHL}	Propagation Delay I _n to Z or Z	3.3	1.0	16.5	
		5.0	1.0	12.0	ns
t _{PZH}	Output Enable Time OE to Z or Z	3.3	1.0	13.0	
		5.0	1.0	10.0	ns
t _{PZL}	Output Enable Time $\overline{\sf OE}$ to Z or $\overline{\sf Z}$	3.3	1.0	13.0	
		5.0	1.0	10.0	ns
t _{PHZ}	Output Disable Time \overline{OE} to Z or \overline{Z}	3.3	3.5	14.0	
		5.0	2.5	11.0	ns
t _{PLZ}	Output Disable Time OE to Z or Z	3.3	4.0	13.0	
		5.0	3.0	10.0	ns

⁽¹⁾ Voltage Range 3.3 is 3.3V ± 0.3 V Voltage Range 5.0 is 5.0V ± 0.5 V.

AC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	(V) (1)	54/	ACT	
			T _A = -55°C to +125°C C _L = 50 pF		Units
			Min	Max	
t _{PLH}	Propagation Delay S_n to Z or \overline{Z}	5.0	1.0	18.0	ns
t _{PHL}	Propagation Delay S_n to Z or \overline{Z}	5.0	1.0	18.0	ns
t _{PLH}	Propagation Delay I_n to Z or \overline{Z}	5.0	1.0	13.5	ns
t _{PHL}	Propagation Delay I_n to Z or \overline{Z}	5.0	1.0	13.5	ns
t _{PZH}	Output Enable Time \overline{OE} to Z or \overline{Z}	5.0	1.0	10.0	ns
t _{PZL}	Output Enable Time \overline{OE} to Z or \overline{Z}	5.0	1.0	9.5	ns

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⁽¹⁾ Voltage Range 5.0 is $5.0V \pm 0.5V$.



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AC ELECTRICAL CHARACTERISTICS (continued)

			54/			
Symbol	Parameter	V _C C ₍₁₎	T _A = -55°C to +125°C C _L = 50 pF		Units	
			Min	Max		
t _{PHZ}	Output Disable Time OE to Z or Z	5.0	1.0	12.5	ns	
t_{PLZ}	Output Disable Time \overline{OE} to Z or \overline{Z}	5.0	1.0	8.5	ns	

CAPACITANCE

Symbol	Parameter	Тур	Units	Conditions
C _{IN}	Input Capacitance	4.5	pF	V _{CC} = OPEN
C _{PD}	Power Dissipation Capacitance	70.0	pF	V _{CC} = 5.0V



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REVISION HISTORY

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•	Changed layout of National Data Sheet to TI format	7

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